NSN 5961-01-512-3190

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-512-3190 **Inclosure Material:** Plastic **Overall Length:** Between 0.159 inches and 0.181 inches **Overall Height:** Between 0.075 inches and 0.096 inches **Overall Width:** Between 0.130 inches and 0.156 inches **End Application:** 1520-01-355-8250 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 10.00 amperes forward current, average of standard range and 2.00 amperes forward current, average and 50.00 amperes source cutoff current peak **Terminal Type And Quantity:** 2 bonding pad Shelf Life: N/a **Unit Of Measure:** Demilitarization:

No

Fiig:

A110a0